



MS ISSUE FEE
PATENT
1781-0247P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: Soo Jin CHUA et al. Conf.: 5461

Appl. No.: 10/633,652 Group: 2812

Filed: August 5, 2003 Examiner: MULPURI, S.

For: FORMING INDIUM NITRIDE (INN) AND INDIUM
GALLIUM NITRIDE (INGAN) QUANTUM DOTS
GROWN BY METAL-ORGANIC-VAPOR-
PHASE=EPITAXY (MOCVD)

LARGE ENTITY TRANSMITTAL FORM

HANDCARRY TO:

U.S. Patent and Trademark Office
2011 South Clark Place
Customer Window
Crystal Plaza Two, Lobby, Room 1B03
Arlington, VA 22202

September 29, 2004

Sir:

Transmitted herewith please find an amendment in the above-
identified application.

- The enclosed document is being transmitted via the Certificate of Mailing provisions of 37 C.F.R. § 1.8.
- The enclosed document is being transmitted via facsimile.

The fee has been calculated as shown below:

	CLAIMS REMAINING AFTER AMENDMENT	HIGHEST NUMBER PREVIOUSLY PAID FOR			PRESENT EXTRA	RATE	ADDITIONAL FEE
TOTAL	14	-	20	=	0	\$ 18	\$0.00
INDEPENDENT	4	-	4	=	0	\$ 86	\$0.00
<input type="checkbox"/> FIRST PRESENTATION OF A MULTIPLE DEPENDENT CLAIM						\$290	\$0.00
						TOTAL	\$0.00

- No fee is required.
- A check in the amount of \$0.00 is enclosed.
- Please charge Deposit Account No. 02-2448 in the amount of \$0.00. This form is submitted in triplicate.

If necessary, the Commissioner is hereby authorized in this, concurrent, and future replies, to charge payment or credit any overpayment to Deposit Account No. 02-2448 for any additional fees required under 37 C.F.R. § 1.16 or under 37 C.F.R. § 1.17; particularly, extension of time fees.

Respectfully submitted,

BIRCH, STEWART, KOLASCH & BIRCH, LLP

By Mark J. Nuell
Mark J. Nuell, #36,623

DRN/mua
1781-0247P

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Attachment(s)

(Rev. 02/08/2004)



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AMENDMENT UNDER 37 C.F.R. § 1.312

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U.S. Patent and Trademark Office
2011 South Clark Place
Customer Window, MS ISSUE FEE
Crystal Plaza Two, Lobby, Room 1B03
Arlington, VA 22202

September 29, 2004

Sir:

Pursuant to the provisions of 37 C.F.R. § 1.312, the following amendments and remarks are respectfully submitted in connection with the above-identified application. It is respectfully requested that the following amendments be entered without withdrawing the application from issue.

This amendment includes Amendments to the Specification; Remarks; Substitute Specification and three (3) Replacement Sheets of Drawings.